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### 1. Introduction

Silicon carbon fibres are one of the best candidates for the reinforcement of continuous-fibre-reinforced ceramic-matrix composites (CMCs), because of their high tensile strength, high elastic modulus, and good thermal stability, especially near-stoichiometric SiC fibres, which render them widely applicable in harsh radiation environments, as components of light water reactor fuel cladding and channel boxes, fuel and invessel components in advanced fission reactors, and other extreme radiation services.<sup>1-10</sup> Polymer-derived method has been regarded as the most successful approach for the synthesis of continuous SiC fibres with a fine diameter. This was first introduced by Yajima<sup>11</sup> and later commercialized under the trade names, Nicalon, Tyranno, and Sylramic. In particular, as one of the third-generation SiC fibres, Hi-Nicalon Type S (Nippon Carbon Co., Tokyo, Japan)<sup>12-14</sup> has low oxygen content, near-stoichiometric chemical composition, and high crystallinity, exhibiting improved thermal stability and creep resistance up to 1400 °C. Thus, near-stoichiometric SiC fibres can satisfy many of the requirements for the use of ceramic matrix composites in high-temperature structural applications and have attracted sustained attention.<sup>15-18</sup>

However, the application of Hi-Nicalon Type S is still limited by the signicantly high cost of production. Hi-Nicalon Type S

## Preparation and characterization of nearstoichiometric silicon carbon fibres

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Near-stoichiometric SiC fibres (CVC-S fibres) were successfully prepared by pyrolysing chemical-vapourcured polycarbosilane fibres under hydrogen and subsequent heat treatment in inert atmosphere at 1500  $^{\circ}$ C. The composition and properties of the obtained fibres were determined by Auger electron spectroscopy, X-ray photoelectron spectroscopy, scanning electron microscopy, transmission electron microscopy, tensile strength testing, and X-ray diffraction analysis. The results reveal that the CVC-S fibres with C/Si of 1.06 and O of 1.11 wt% have high tensile strength (2.6 GPa), high tensile modulus (321 GPa), and a highly crystalline structure (crystallite size,  $\sim$ 14 nm.) In addition, the high-temperature behaviour of the CVC-S fibre was also investigated via heat treatment in argon and air at different temperatures. In particular, the fibres retain  $\sim$  2.2 GPa of their original strength after heating at 1600 °C for 1 h under argon. When argon was replaced by air, the tensile strength of the fibres could still be maintained at  $\sim$ 1.1 GPa after annealing at 1400 °C. The more economical and practical approach along with the excellent performance of the obtained fibres render the CVC-S fibres promising materials for high-temperature applications. PAPER<br>
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fibres were prepared by melt-spinning polycarbosilane, followed by radiation-curing using an electron beam and subsequent pyrolysis in hydrogen and then in argon.<sup>19</sup> The electron radiation was the main factor in the considerably high cost of Hi-Nicalon Type S, in consideration of the low irradiation dose, long period of irradiation, and expensive equipment. In order to circumvent this, researchers adopted different technologies for lowering the cost. To enhance the curing efficiency of the electron beam irradiation process at a low dose rate, Su<sup>20</sup> prepared SiC fibres using a curing route of electron irradiation in an atmosphere with a low concentration of oxygen. However, the oxygen content of the resultant SiC fibres was 10.03%. In addition, low-oxygen SiC fibre can be prepared by the pyrolysis of polycarbosilane (PCS) fibres cured with chemical vapour curing (CVC), however, these CVC-cured fibres are not nearstoichiometric fibres and the thermal stability needs to be improved further.<sup>21-23</sup> Therefore, near-stoichiometric SiC fibres with low cost and high performance continue to be the focus of researchers.

In this study, a new type of near-stoichiometric SiC fibres, namely CVC-S SiC fibres, were prepared via pyrolysis of chemical-vapour-cured polycarbosilane fibres in an atmosphere containing hydrogen and subsequently heat-treated in an inert atmosphere. As far as we are aware, few works have been adopted to prepare near-stoichiometric SiC fibres by using CVCcured PCS fibres as raw materials. Specially, it is really difficult to cured PCS fibres completely via CVC process. More importantly, CVC process usually used unsaturated alkene or alkyne atmospheres to react with PCS fibres, which would introduce



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additional carbon to the fibres. Subsequently, the carbon elimination conducted in hydrogen atmosphere will result in higher mass loss, which will generate more defects, thus lower the fibres strength. However, the low production cost of nearstoichiometric SiC fibres by CVC process has attracted special attentions. Recently, by choosing cyclohexene gas, applying advanced equipment and strictly controlling technics, high performance near-stoichiometric SiC fibres, namely CVC-S SiC fibres, was successfully prepared from CVC-cured PCS fibres. In addition, the composition and properties of the obtained fibres as well as its comparison with Hi-Nicalon Type S were investigated. The more economical and practical approach along with the excellent performance of the obtained fibres render the CVC-S fibres promising materials for high-temperature applications. **BSC Arbaness**<br> **Consider the filtres Subsequent)**, the carbon coupled with an Ar<sup>t</sup> spanning and for depth profiling a<br>
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#### 2. Experimental procedure

#### 2.1 Sample preparation

The PCS fibres used in this study were produced following the procedure of Yajima.<sup>24</sup> Then, the PCS fibres were cured by heating in a tubular furnace up to 350 °C at the rate of 25 °C h<sup>-</sup> under the flow of nitrogen mixed with cyclohexene vapours.<sup>25</sup> The composition and properties of the obtained CVC-cured bres are provided in Table 1. To prepare near-stoichiometric SiC fibres, the CVC-cured fibres were heated under a gas mixture (70 vol%  $H_2$  and 30 vol% Ar) up to 800 °C at the rate of 60 °C h<sup>-1</sup> and subsequently annealed at 1500 °C at the rate of 300 °C  $h^{-1}$  under inert atmosphere.

#### 2.2 Annealing treatments

The high-temperature treatment under different environments was carried out as follows: the fibres were charged into a graphite crucible and heated under argon at 1500, 1600, 1700, and 1800 °C for 1 h.

#### 2.3 Analysis and characterization

The bulk composition of the fibres was determined by chemical analysis. Quantitative analysis of carbon was carried out using an EMIA-320V carbon/sulfur analyzer (Horiba, Japan), and oxygen was measured using an EMIA-820 oxygen/nitrogen analyzer (Horiba, Japan). The content of silicon was obtained by the alkali fusion method.

The depth profile of the fibre surfaces was conducted with an Auger electron spectroscope (AES, ULVAC PHI-700, Japan)





coupled with an Ar<sup>+</sup> sputtering gun for depth profiling at a sputtering rate of 13 nm  $min^{-1}$  (sputtering rate reference:  $SiO<sub>2</sub>$ ).

X-ray photoelectron spectroscopy (XPS, Thermo Scientific ESCALAB 250Xi, USA) spectra were recorded using Al K $\alpha$  as the excitation source to detect the surface compositions and chemical bonding states in a few atomic layers. The inner layer of the fibres was revealed by etching for 100 s to XPS analysis by argon ion bombardment at a rate of 0.72 nm  $s^{-1}$ .

Then, the structure of free carbon in the fibres were analyzed by Raman spectrometer (Bruker, Germany) employing a semiconductor laser ( $\lambda = 532$  nm).

The surface and fracture morphologies of the fibres were examined using a scanning electron microscope (SEM, Hitachi FEG S4800, Japan).

Furthermore, transmission electron microscope (TEM) imaging and high-angle annular dark-filed scanning transmission electron microscope (HAADF-STEM) imaging was performed using a Titan G2 60-300 high resolution microscope (FEI, USA) equipped with an energy-dispersive spectroscope (EDS). Samples for TEM and STEM observations were crosssection slice formed by using focused ion beam (FIB) sputtering the fibres.

The tensile strength of the 25 mm long fibres was measured at room-temperature with a universal strength machine (Testometrix Micro 350, UK) using a load cell of 5 N and a crosshead speed of 5 mm  $min^{-1}$ . The average tensile strength was obtained from the measured results of 24 filaments.

The crystal structure of the fibres was characterized by an Xray diffractometer (XRD, Bruker D8ADVANCE, Germany) using monochromatic Cu K $\alpha$  radiation ( $\lambda = 1.5406$  Å), and the apparent crystallite size of  $\beta$ -SiC was estimated from the halfvalue width of the (220) peak employing the Scherrer's formula.

The thermal stability of the SiC fibres was evaluated in a high-temperature carbon-resistant furnace under argon. The oxidation test was performed in a muffle furnace under air. In addition, the fibres were placed in an alumina boat and were maintained at the annealing temperature (1000, 1100, 1200, 1300, 1400, and 1500 °C) for 1 h under air.

### 3. Results and discussion

#### 3.1 Characterization of CVC-S SiC fibres

The composition and properties of the prepared CVC-S SiC bres are listed in Table 2. The contents of silicon, carbon, and





Fig. 1 AES depth profiles recorded from the surface of CVC-S SiC fibre.

oxygen were found to be  $65.68$ , 29.96, and  $1.11$  wt%, respectively; hence, CVC-S fibres had a molar composition of  $\text{SiC}_{1.06}\text{O}_{0.03}$ , indicating that the fibres comprised of nearstoichiometric SiC with low oxygen content. Remarkably, CVC-S fibres had slightly higher oxygen content (about 0.9 wt%) compared with Hi-Nicalon Type S, probably due to the relatively high oxygen content of the CVC-cured fibres. Besides, CVC-S SiC fibres have excellent mechanical properties, e.g., the tensile strength and Young's modulus are 2.6 GPa and 321 GPa respectively. It should be noted that the tensile strength of CVC-S SiC fibres was as high as Hi-Nicalon Type S (2.6 GPa). The excellent mechanical properties might be related to the dense microstructure, which was confirmed by their high density (2.86  $\rm g~cm^{-3}$ ). In addition, the modulus of CVC-S SiC fibres was Paper<br>
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lower than Hi-Nicalon Type S (420 GPa), which might be caused by their different composition and structure. Since CVC curing method would introduce additional carbon as well as more oxygen, which might lower the Young's modulus.

Auger electron spectroscopy (AES) was performed on CVC-S fibres to better analyse the composition of the fibres. Fig. 1 shows the AES depth profiles for CVC-S SiC fibres, which suggest that the fibre surface was enriched in both carbon and oxygen up to  $\sim$ 10 nm in thickness. This part rapidly vanished after sputtering, with the composition of near-stoichiometric SiC and low content of oxygen becoming constant, indicating the outstanding thermal stability of the CVC-S fibres.

According to previous studies, cyclohexyl group can be introduced into the PCS skeleton during CVC, and it may be converted to free carbon embedded in the Si–C networks in a subsequent pyrolysis process.<sup>26,27</sup> Considering the characteristics of the gas–solid reaction, cyclohexyl group will be incorporated to a greater extent on the surface, generating a thicker layer with excess carbon. In contrast, a carbon layer was also observed on the surface of Hi-Nicalon Type S, with its thickness being approximately 150 nm,<sup>19</sup> which might be associated with the high-temperature properties of SiC fibres. Thus, the CVC-S SiC fibres contained near-stoichiometric SiC and low oxygen content, with carbon- and oxygen-enriched surface layers.

The composition and microstructure of the surface of the SiC fibres significantly influenced their properties. For example, the surface composition of SiC fibres affected SiC nucleation and SiO diffusion from the core to fibre surface, which influenced the formation of large grains on the surface.<sup>28</sup> Therefore, X-ray photoelectron spectroscopy (XPS) was used to investigate the



Fig. 2 High-resolution XPS spectra of Si 2p (a and c) and C 1s (b and d) regions for the CVC-S SiC fibres before and after  $Ar^+$  etching

Location	Composition			Si 2p		C <sub>1s</sub>		
	$Si$ (at%)	$C$ (at%)	$O(\text{at}\%)$	SiC	$\text{SiC}_{x}\text{O}_{y}$	C-Si	$C-C$	$C-O$
$0 \text{ nm}$	37.59	44.71	17.70	81.91%	18.09%	52.24%	45.18%	2.58%
70 nm	47.98	44.58	7.44	86.23%	13.77%	69.92%	30.08%	

Table 3 Elemental composition of CVC-S SiC fibres as determined by XPS analysis

surface chemical bonding of CVC-S SiC fibres, and the results are shown in Fig. 2. In the XPS Si 2p spectra (Fig. 2a), a peak at a binding energy (BE) of 100.6 eV is observed corresponding to Si in bulk SiC. The peak at 101.3 eV is attributed to the oxidation state of silicon intermediate between its oxidation state in  $SiO<sub>2</sub>$ and in SiC, and originates from  $\text{SiC}_x\text{O}_y$ .<sup>29</sup> Therefore, the presence of amorphous  $\text{SiC}_x\text{O}_y$  phases on the fibre surface can be inferred. The C 1s spectrum is shown in Fig. 2b, and the peaks at 282.3, 284.3, and 285.8 eV correspond to C-Si,  $sp^2$  C=C, and  $C$ –O bonding configurations, respectively.<sup>30,31</sup> According to these results, the fibre surface can be concluded to consist of SiC,  $\text{SiC}_x\text{O}_y$ , and free carbon.

Apart from the surface layer (0 nm), the elemental composition of the inner layer (approximately 70 nm from the surface) of the CVC-S SiC fibres was examined by XPS and the results are tabulated in Table 3. As shown, the content of Si increased, however the content of O decreased, and the C/Si mole ratio is close to 1, indicating the presence of more SiC and less  $\text{SiC}_x\text{O}_y$ in the interior layer at a depth of 70 nm from the surface. According to the XPS Si 2p spectra (Fig. 2c), the type of bonding did not change. However, no C–O bonding is observed in the spectrum of C 1s (Fig. 2d). Furthermore, Table 2 shows the mole ratio of the components from the XPS Si 2p spectra to be  $\text{SiC : } \text{SiC}_x\text{O}_y = 1 : 0.22$  (0 nm, topmost surface layer) and  $\text{SiC}: \text{SiC}_x\text{O}_y = 1:0.16$  (a layer 70 nm removed from the surface). In brief, the fibres are almost composed of SiC, with a small quantity of  $\text{SiC}_x\text{O}_y$  and free carbon on the surface, which is also in agreement with the results of AES depth profiling.

Free carbon phases would affect many of the properties of SiC fibres. Raman spectroscopy was used to analyse the microstructure of free carbon. The Raman spectra of SiC fibres (Fig. 3) consist of two peaks at  $\sim$ 1345 and 1590  $\rm cm^{-1}$ , which are attributed to the D (disordered) and G (graphitic) bands,



Fig. 3 Raman spectra of CVC-S SiC fibres.

respectively; hence, the carbon consists of disordered carbon and micro-crystalline graphite embedded in the disordered carbon. In order to obtain more information, the Raman spectra were fitted using the Lorentzian function for D band and the Breit-Wigner-Fano function for G band,<sup>32</sup> and the Raman characteristics of the two bands are compiled in Table 4. The full width at half maximum (FWHM) of the G band and integrated intensity ratio of the D to G band  $(I_D/I_G)$  for the surface, as calculated from the Raman spectra are 71.5 and 2.11  $\rm cm^{-1}$ , respectively. In addition, the FWHM of G band of the bulk fibres is larger than that of the surface, indicating that the graphitization of free carbon of surface was higher than that of bulk. In general,  $I_D/I_G$  is used to approximate the crystallite size of micro-crystalline graphite, using the expression,<sup>33</sup>  $L_a$  (nm) =  $(2.4 \times 10^{-10})\lambda^4 (I_D/I_G)^{-1}$ , where,  $L_a$  is the crystallite size and  $\lambda$ (532 nm) is the wavelength of the laser used in the Raman experiment. Based on this expression, the value of  $L<sub>a</sub>$  of the surface and bulk were both calculated to be  $\sim$ 9 nm. **PSC Advances**<br>
Table 3 Lemental connection of CVC-5 SIC fizers as determined by *NS* analysis<br>  $\frac{1}{2}$  m.  $\frac{1}{2}$  m.<br>  $\frac{1}{2}$  m.  $\frac{1}{2}$  m.<br>  $\frac{1}{2}$  m.  $\frac{1}{2}$  m.<br>  $\frac{1}{2}$  m.  $\frac{1}{2}$  m.<br>  $\frac{1}{2}$  m.  $\frac{$ 

As shown in Fig. 4a, the fibre surfaces are smooth and dense without any obvious cracks or pores. The fracture cross-section in Fig. 4b shows distinct mirror and hackle features, which are recognized as typical fracture traits of dense ceramic fibres.<sup>34</sup> Moreover, no visible pores or defects are observed on the fracture surface, indicating the high structural uniformity of the fibres, which was similar to Hi-Nicalon Type S.

Fig. 5a shows the TEM micrograph and selected-area electron diffraction pattern (SAED) of the as-prepared fibres. The SAED pattern shows three main rings corresponding to the Bragg reflections of the (111), (220), and (311) planes of  $\beta$ -SiC, indicating that the observed areas consist of  $\beta$ -SiC grains. The fibre structure was further analyzed by HRTEM (Fig. 5b). It is clear that the as-prepared fibre is composed of silicon carbide, free carbon, and an amorphous intergranular phase. The lattice parameter of the SiC,  $0.25$  nm, was identified as the  $(111)$  planes of the  $\beta$ -SiC nanocrystal. Free carbon was stacked by slightly distorted carbon layers and the intergranular phase might be the amorphous  $\text{SiC}_x\text{O}_y$  phase. Furthermore, it is obvious that the primary phase of the fibres is silicon carbon and only

Table 4 Raman characteristics of the free carbon phases at different depths from the surface for CVC-S SiC fibres

		D peak $\rm (cm^{-1})$		G peak $\rm (cm^{-1})$	
Test points	Position	<b>FWHM</b>	Position	<b>FWHM</b>	$I_{\rm D}/I_{\rm G}$
Surface	1343	73.9	1590	71.5	2.11
Bulk	1345	74.2	1593	73.6	2.18



Fig. 4 SEM micrographs of the surface (a) and cross-section (b) of CVC-S SiC fibres.



Fig. 5 TEM image and corresponding SAED pattern (a) and HRTEM image (b) of CVC-S SiC fibres.

a small quantity of free carbon and amorphous phases, which is in good agreement with the XPS analysis, as discussed previously.

#### 3.2 High-temperature behaviour of CVC-S SiC fibres

3.2.1 Mechanical properties. For the high-temperature operation of bres, retention of strength and reliability throughout their service life is the most critical factor. The variations in tensile strength of the fibres annealed under either

argon or air as a function of the heating temperature are shown in Fig. 6. It is evident that CVC-S fibres have excellent thermal stability and oxidation resistance.

Fig. 6a shows the tensile strength of the fibres after the thermal test in argon atmosphere. The failure stress decreased very slowly below 1600 $\degree$ C in argon. The fibres maintained 2.3 GPa and 2.2 GPa after 1 h at 1500 and 1600  $^{\circ}$ C, respectively. Moreover, although CVC-S fibres retained good strength (approximately 1 GPa) even after heating to 1700  $\degree$ C, increased deterioration of the strength is observed. Specifically, the fibres



Fig. 6 Tensile strength changes of CVC-S fibres after heat treatment in argon (a) and air (b) for 1 h.



Fig. 7 Surface morphologies of CVC-S SiC fibres annealed in argon at various temperatures for 1 h.

treated in argon at 1700 and 1800  $^{\circ}$ C retained 1.0 GPa and 0.8 GPa, respectively. The decline in the strength might be caused by the decomposition of the  $\text{SiC}_x\text{O}_y$  phase after the hightemperature treatment (as shown in eqn (1)). Overall, CVC-S fibres had excellent thermal stability at  $\sim$ 1600 °C, which was matched by that of Hi-Nicalon Type S, but the strength of CVC-S fibres after 1 h exposure in argon gas above 1700  $\degree$ C was lower than that of the latter.<sup>35</sup> This difference might be caused by the composition of a bit more oxygen (1.11 wt%), which was mainly formed as  $\text{SiC}_x\text{O}_y$  phase. And the decomposition of the  $\text{SiC}_x\text{O}_y$ phase at the high temperature might lead to some defects and flaws in CVC-S fibres. Even so, CVC-S fibres still had good mechanical properties in high-temperature condition.

$$
\text{SiC}_x\text{O}_y \rightarrow \text{SiC (s)} + \text{C (s)} + \text{SiO (g)} + \text{CO (g)} \tag{1}
$$

In contrast, the results of oxidation test shown in Fig. 6b suggest a different trend than that of Fig. 6a. The tensile strength of the fibres slightly increased with an increase in the temperature to 1100 $\degree$ C in air, possibly due to the generation of an oxidation layer which remedied the defect in the surface to some extent. Subsequently, the tensile strength decreased gradually with increasing temperature, which is possibly related to the thickness of the oxidation layer. After heating at 1400-1500  $\degree$ C in air for 1 h, the tensile strengths of the fibres were found to be maintained at  $\sim$ 1.1 GPa. Compared to Hi-Nicalon Type S (strength of  $\sim$ 1.1 GPa at 1500 °C in air),<sup>35</sup> CVC-S fibres



Fig. 8 SEM micrographs of the cross-section of CVC-S SiC fibres annealed in air at various temperatures for 1 h.





had the similar properties, which showed the good oxidation resistance.

3.2.2 Fibre morphology. The heated fibres were also investigated by SEM. Fig. 7 shows the SEM images of the fibres annealed in argon at different temperatures for 1 h. Negligible differences are observed in the surface features of the fibres after heating at 1500 and 1600 °C in argon; thus, the fibres maintained most of their original strength. Moreover, the fibre surfaces became coarser with increasing heat treatment temperature. Furthermore, after heat treatment at 1700 °C or more, the fibre surface exhibited a porous and coarse microstructure and much larger particles, which could be ascribed to the decomposition of the  $\text{SiC}_x\text{O}_y$  phase (as shown in eqn (1)) and the growth of  $\beta$ -SiC grains. As previously reported, these large SiC particles are produced by the gas-phase reaction shown in eqn  $(2)$ ,<sup>36</sup> which might be the reason why the fibres maintained only approximately one third of the strength after 1 h above 1700 °C.

$$
\text{SiO (g)} + 3\text{CO (g)} \rightarrow \text{SiC (s)} + 2\text{CO}_2 \text{ (g)} \tag{2}
$$

However, Fig. 8 shows that when exposed to air at different temperatures, an oxidation layer composed of silica is generated on the surface, without any large particles. The oxidation layer is mainly produced by the passive-oxidation reaction shown in eqn (3). Moreover, it is obvious that the thickness of the oxidation layers increased significantly with temperature, under air. The strength is in good agreement with the thickness of the oxidation layer, which might be the reason for the decline in the strength.

$$
2SiC(s) + 3O_2(g) \to 2SiO_2(s) + 2CO(g)
$$
 (3)

3.2.3 Chemical composition. The results of bulk elemental chemical analysis of the as-prepared and heat-treated CVC-S fibres are tabulated in Table 5. The contents of carbon and silicon were found to be maintained at the same level in both



Fig. 9 XRD patterns (a and c) and average size of  $\beta$ -SiC crystalline (b) of CVC-S SiC fibres before and after heat treatment: (a and b) under argon and (c) under air.

atmospheric conditions. However, the oxygen content decreased slightly with increasing temperature under argon. It is well-known that oxygen exists in the form of  $\text{SiC}_x\text{O}_y$  phase and can be eliminated as SiO and CO because of the decomposition of  $\text{SiC}_x\text{O}_y$  phase at a high temperature. However, the oxygen content of the CVC-S SiC fibres annealed under air gradually increased with increasing temperature and became  $\sim$  6.84 wt% at 1500 $\degree$ C, owing to the passive-oxidation.

3.2.4 X-ray diffraction. The phase of the structure was studied in detail by XRD, as shown in Fig. 9. The as-prepared fibres present three main diffraction peaks at  $2\theta = 35.5^{\circ}$ , 59.8°, and 71.8°, which are assigned to the  $(111)$ ,  $(220)$ , and (311) planes of the  $\beta$ -SiC phase, respectively. And this is consistent with the results of TEM (Fig. 5). The XRD peaks become shaper with increasing temperature in argon. When the annealing temperature was elevated to  $1600\,^{\circ}\text{C}$ , other peaks that could be indexed to the (200) and (222) planes of the  $\beta$ -SiC phase also appeared. The apparent crystallite size of  $\beta$ -SiC was calculated from the FWHM of the  $(220)$  peak of  $\beta$ -SiC using the Scherrer's formula and is shown in Fig. 9b. Obviously, the  $\beta$ -SiC grains grew into larger crystals and the growth rate was found to increase with increasing heat treatment temperature. This grain growth is attributed to the coalescence of the grains and the decomposition of the  $\text{SiC}_x\text{O}_y$  phase. However, the grain growth rate of CVC-S fibres was found to be higher than that of Hi-Nicalon Type S fibres, the grain size of which increased up to 26 nm when heated at 1800  $^{\circ}$ C. These results are in perfect accordance with the deterioration in the strength. In contrast, as shown in Fig. 9c, there was very small variation in the size of the  $\beta$ -SiC grains when the CVC-S fibres were heat-treated from 1000 to 1500 °C under air. In addition, the peak at  $2\theta = 22.0^{\circ}$ , which belongs to the  $\alpha$ -cristobalite phase confirms that indeed  $SiO<sub>2</sub>$  is generated in the fibres after exposure to air at the heating temperature for 1 h. The above results are consistent with the SEM images. Moreover, it should not be neglected that a peak at  $2\theta = 26.6^{\circ}$ , which was assigned to the (002) plane of graphite,<sup>37</sup> appeared in both Fig. 9a and c, confirming the existence of some surplus carbon in CVC-S fibres. With the treated temperatures increased in argon or air, the shape and position of the diffraction peak had not changed, indicating no evolution graphite phase and its crystallite size, which further confirmed the outstanding thermal stability of CVC-S fibres in argon and air. **Excelse the control of the statistical on 14 May 2018.** The statistical on 14 May 2018. The statistical on 14 May 2018. The statistical or 14 May 2018. The statistical published in the mechanismism of the statistical publ

#### 4. Conclusions

The CVC-S silicon carbon fibres with near-stoichiometric composition were prepared by heating chemical-vapour-cured polycarbosilane fibres in hydrogen and then in an inert atmosphere. The general properties and microstructural evolution of the CVC-S silicon carbon fibres were characterized at high temperatures under argon and air atmospheres. The CVC-S bres were found to be composed of SiC and an amorphous  $\text{SiC}_x\text{O}_y$  structure with traces of free carbon on the surface. The tensile strength was found to be 2.6 GPa. When heated to high temperatures for 1 h, the CVC-S fibres showed significant differences in the mechanical properties and microstructure depending on the surrounding atmosphere. With increasing heat treatment temperature in argon, the fibre surfaces became coarser and new defects such as large SiC particles appeared on

the fibre surface, accompanied by the decomposition of the  $\text{SiC}_x\text{O}_y$  phase. The  $\beta$ -SiC grains tended to grow into larger crystals with increasing temperature in argon because of the coalescence of the grains and the decomposition of the  $\text{SiC}_x\text{O}_y$ phase. We established that the mechanical properties of the CVC-S SiC fibres are closely related to their microstructures. After annealing at 1600  $^{\circ}$ C under argon, the fibres still retained tensile strength of  $\sim$ 2.2 GPa. When argon was replaced by air, the fibres retained tensile strength of  $\sim$ 1.1 GPa at 1400 °C. The SEM observations indicated that the thickness of the oxidation layer increased with the temperature, which led to the decline in the strength of the fibres. Based on the microstructural analyses, it is likely that the  $\beta$ -SiC grains grew, and the surface flaws and the surface composition are responsible for the deterioration of the fibre strength after heating at high temperatures in argon or air. These results reveal the potential of the CVC-S silicon carbon fibres with near-stoichiometric composition and high tensile strength for application in high-temperature CMCs. In summary, this process is highly cost-effective for the large-scale industrial production of near-stoichiometric SiC fibres.

### Conflicts of interest

There are no conflicts to declare.

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